

塑封高效率整流二极管

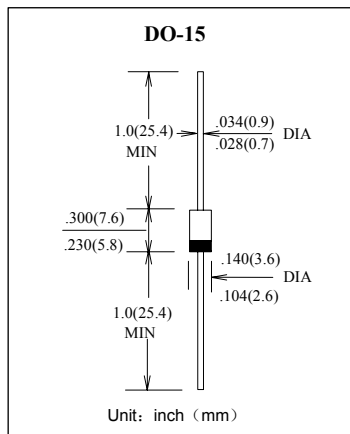
反向电压 50 --- 600 V

正向电流 1.1 --- 1.3 A

Plastic High-Efficiency Rectifier

Reverse Voltage 50 to 600V

Forward Current 1.1 to 1.3A



特征 Features

- 低的反向漏电流 Low reverse leakage
- 较强的正向浪涌承受能力 High forward surge capability
- 高温焊接保证 High temperature soldering guaranteed:  
250°C/10 秒, 0.375" (9.5mm) 引线长度。  
250°C/10 seconds, 0.375" (9.5mm) lead length,
- 引线可承受5 磅 (2.3kg) 拉力。 5 lbs. (2.3kg) tension

机械数据 Mechanical Data

- 端子: 镀锡轴向引线 Terminals: Plated axial leads
- 极性: 色环端为负极 Polarity: Color band denotes cathode end
- 安装位置: 任意 Mounting Position: Any

极限值和温度特性 TA = 25°C 除非另有规定。

Maximum Ratings & Thermal Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

	符号 Symbols	BYV27 -50	BYV27 -100	BYV27 -150	BYV27 -200	BYV27 -300	BYV27 -400	BYV27 -500	BYV27 -600	单位 Unit
最大可重复峰值反向电压 Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	150	200	300	400	500	600	V
最大均方根电压 Maximum RMS voltage	V <sub>RMS</sub>	35	70	105	140	210	280	350	420	V
最大直流阻断电压 Maximum DC blocking voltage	V <sub>DC</sub>	50	100	150	200	300	400	500	600	V
最大正向平均整流电流 Maximum average forward rectified current	I <sub>F(AV)</sub>	1.3			1.25			1.1		A
峰值正向浪涌电流 8.3ms单一正弦半波 Peak forward surge current 8.3 ms single half sine-wave	I <sub>FSM</sub>	50						40		A
最大反向峰值电流 @TA=75°C Maximum peak reverse current full cycle	I <sub>R(AV)</sub>	30								µA
典型热阻 Typical thermal resistance	R <sub>θJA</sub>	45								°C/W
工作结温和存储温度 Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-50 --- +150								°C

电特性 TA = 25°C 除非另有规定。

Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

	符号 Symbols	BYV27 -50	BYV27 -100	BYV27 -150	BYV27 -200	BYV27 -300	BYV27 -400	BYV27 -500	BYV27 -600	单位 Unit
最大正向电压 I <sub>F</sub> = 2.0A Maximum forward voltage	V <sub>F</sub>	0.98			1.05		1.25			V
最大反向电流 TA= 25°C Maximum reverse current TA=100°C	I <sub>R</sub>	5.0						150		µA
最大反向恢复时间 I <sub>F</sub> =0.5A I <sub>R</sub> =1.0A I <sub>RR</sub> =0.25A MAX. Reverse Recovery Time	trr	35			50					nS
典型结电容 V <sub>R</sub> = 0V, f = 1MHz Type junction capacitance	C <sub>j</sub>	100			80		65			pF

特性曲线 Characteristic Curves

